

INCHANGE SEMICONDUCTOR

isc Silicon PNP Darlington Power Transistor

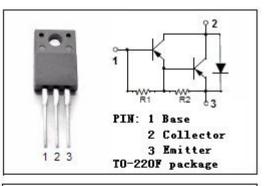
2SB1024

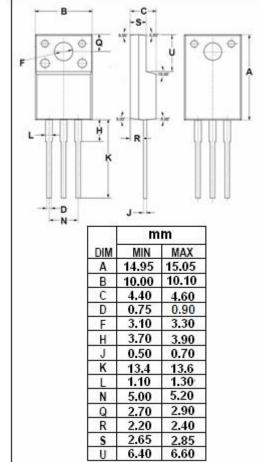
DESCRIPTION

- Low Collector Saturation Voltage-
 - : V_{CE(sat)}= -1.5V(Max.)@ I_C= -3A
- High DC Current Gain-
 - : h_{FE} = 2000(Min)@ (V_{CE}= -2V, I_C= -1A)
- Complement to Type 2SD1414
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Designed for power amplifier applications.





ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{сво}	Collector-Base Voltage -100		V	
V _{CEO}	Collector-Emitter Voltage	V		
V _{EBO}	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-4	А	
I _{CM}	Collector Current-Peak	-6	А	
I _B	Base Current-Continuous	-0.3	А	
Pc	Collector Power Dissipation @Ta=25℃	2		
	Collector Power Dissipation @T _c =25°C	20	W	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55~150	°C	

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ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA ; I _B = 0	-80			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -3A; I _B = -6mA			-1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = -3A; I _B = -6mA			-2.0	V
I _{СВО}	Collector Cutoff Current	V _{CB} = -100V; I _E = 0			-20	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-2.5	mA
h _{FE-1}	DC Current Gain	I _C = -1A; V _{CE} = -2V	2000			
h _{FE-2}	DC Current Gain	I _C = -3A; V _{CE} = -2V	1000			



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